

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Collector-Base Voltage	BC846	V _{CBO}	80	V
	BC847		50	
	BC848		30	
Collector-Emitter Voltage	BC846	V _{CEO}	65	V
	BC847		45	
	BC848		30	
Emitter-Base Voltage	BC846, BC847	V _{EBO}	6.0	V
	BC848		5.0	
Continuous Collector Current		I _C	100	mA
Peak Collector Current		I _{CM}	200	mA
Peak Emitter Current		I _{EM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

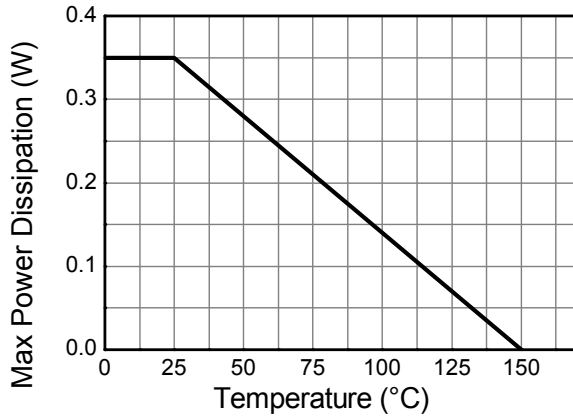
Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	P _D	310	mW
	(Note 7)		350	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{θJA}	403	°C/W
	(Note 7)		357	
Thermal Resistance, Junction to Leads	(Note 8)	R _{θJL}	350	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-65 to +150	°C

ESD Ratings (Note 9)

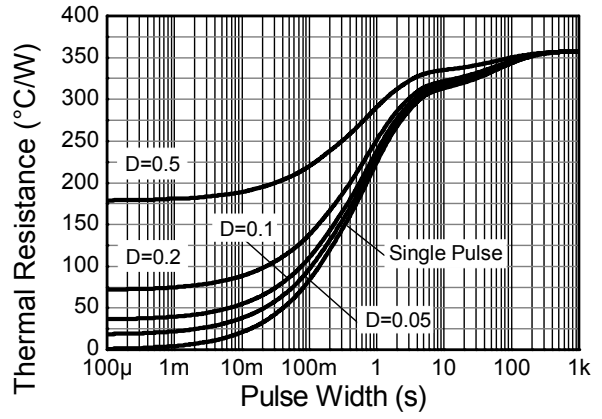
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 7. Same as note (6), except the device is mounted on 15 mm x 15mm 1oz copper.
 8. Thermal resistance from junction to solder-point (at the end of the leads).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

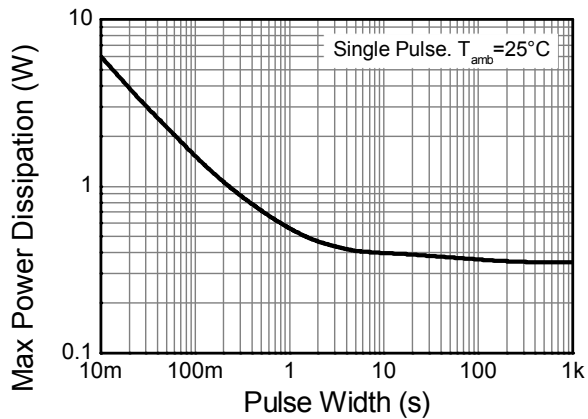
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BC846	BV _{CBO}	80	—	—	V	I _C = 10μA
	BC847		50				
	BC848		30				
Collector-Emitter Breakdown Voltage (Note 10)	BC846	BV _{CEO}	65	—	—	V	I _C = 10mA
	BC847		45				
	BC848		30				
Emitter-Base Breakdown Voltage	BC846 / BC847	BV _{EBO}	6	—	—	V	I _E = 1μA
	BC848		5				
Collector Cutoff Current		I _{CBO}	—	—	15	nA	V _{CB} = 30V
					5	μA	V _{CB} = 30V, T _J = +150°C
Collector Emitter Cutoff Current	BC846	I _{CES}	—	—	15	nA	V _{CE} = 80V
	BC847				15		V _{CE} = 50V
	BC848				15		V _{CE} = 30V
Emitter Base Cutoff Current		I _{EBO}	—	—	100	nA	V _{EB} = 5V
Small Signal Current Gain (Note 10)	BC846A / BC847A / BC848A	h _{fe}	—	200	—	—	I _C = 2.0mA, V _{CE} = 5V f=1.0kHz
	BC846B / BC847B / BC848B			330			
	BC847C / BC848C			600			
Input Impedance (Note 10)	BC846A / BC847A / BC848A	h _{ie}	—	2.7	—	kΩ	
	BC846B / BC847B / BC848B			4.5			
	BC847C / BC848C			8.7			
Output Admittance (Note 10)	BC846A / BC847A / BC848A	h _{oe}	—	18	—	μS	
	BC846B / BC847B / BC848B			30			
	BC847C / BC848C			60			
Reverse Voltage Transfer Ratio (Note 10)	BC846A / BC847A / BC848A	h _{re}	—	1.5x10 ⁻⁴	—	—	
	BC846B / BC847B / BC848B			2x10 ⁻⁴			
	BC847C / BC848C			3x10 ⁻⁴			
DC Current Gain (Note 10)	BC846A / BC847A / BC848A	h _{FE}	110	180	220	—	I _C = 2.0mA, V _{CE} = 5V
	BC846B / BC847B / BC848B		200	290	450		
	BC847C / BC848C		420	520	800		
Collector-Emitter Saturation Voltage (Note 10)		V _{CE(sat)}	—	90	250	mV	I _C = 10mA, I _B = 0.5mA
				200	600		I _C = 100mA, I _B = 5.0mA
Base-Emitter Turn-On Voltage(Note 10)		V _{BE(on)}	580	660	700	mV	I _C = 2mA, V _{CE} = 5V
			—	—	770		I _C = 10mA, V _{CE} = 5V
Base-Emitter Saturation Voltage(Note 10)		V _{BE(sat)}	—	700	—	mV	I _C = 10mA, I _B = 0.5mA
				900			I _C = 100mA, I _B = 5mA
Output Capacitance		C _{obo}	—	3	—	pF	V _{CB} = 10V, f = 1.0MHz
Transition Frequency		f _T	100	300	—	MHz	V _{CE} = 5V, I _C = 10mA, f = 100MHz
Noise Figure		NF	—	2	10	dB	V _{CE} =5V, I _C =200μA R _S =2kΩ, f=1kHz Δf=200Hz

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

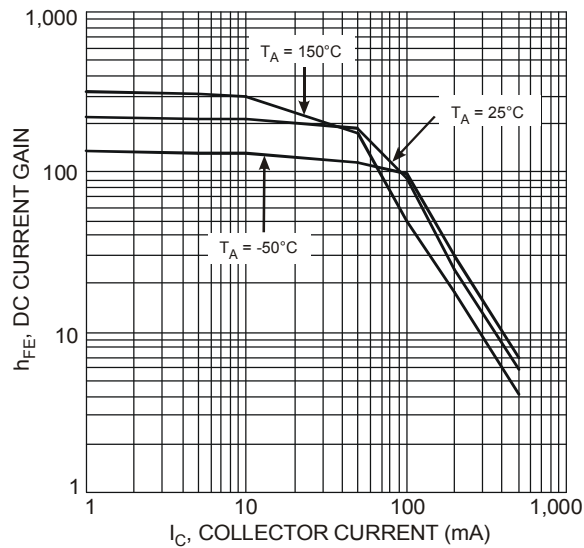


Figure 1 Typical DC Current Gain vs. Collector Current

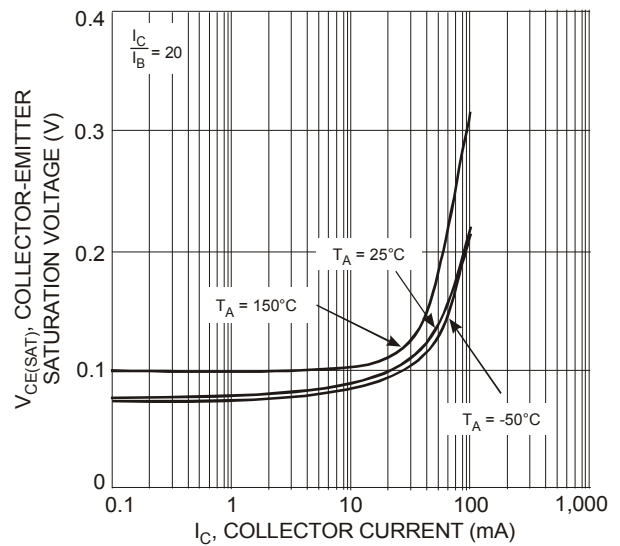


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

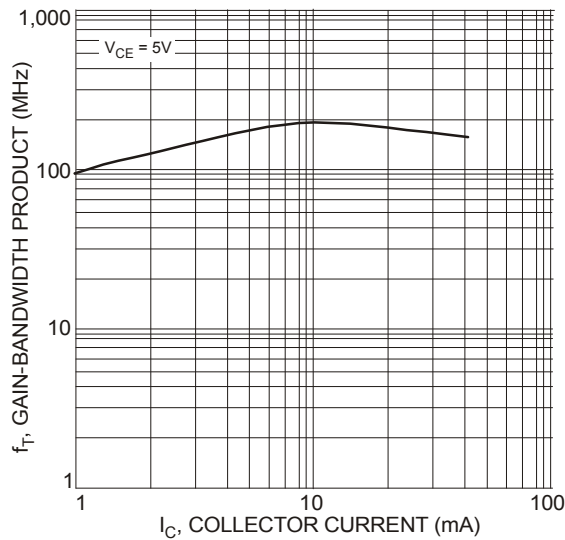
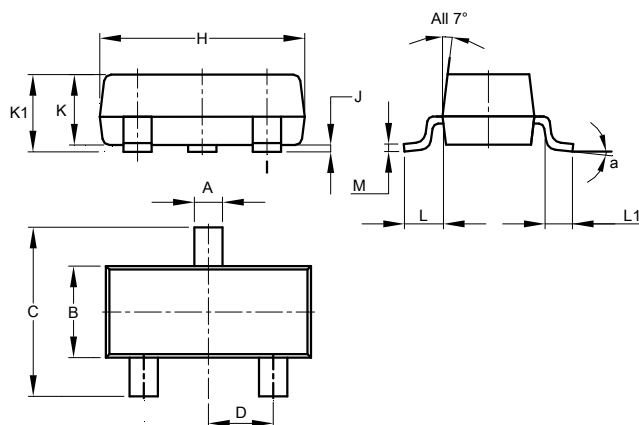


Figure 3 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

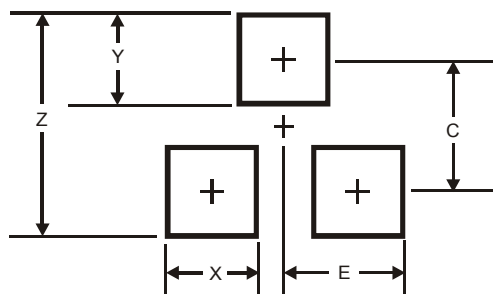
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	8°		
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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